Diode Semiconductor Device - Page 1 of 1



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Inclosure Materi	
Glass	
Overall Length:	
	iches and 0.350 inches
Terminal Length	
1.000 inches	
Overall Diamete	
	inches and 0.265 inches
	ally-electrically Connected To Case:
Cathode	
Mounting Metho	d:
Terminal	
Features Provid	
Hermetically seal	
Semiconductor	Material:
Silicon	
	n Volts Per Characteristic:
100.0 regulator	voltage
Current Rating F	Per Characteristic:
9.00 milliamperes	s source cutoff current horsepower metric
Power Rating Pe	er Characteristic:
1.0 watts small-si	gnal input power, common-collector preset
Maximum Opera	ting Tempurature Per Measurement Point:
175.0 degrees ce	elsius ambient air
Test Data Docur	nent:
81349-mil-s-1950	00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental an	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	and Quantity:
2 uninsulated wire	e lead
Specification Da	ita:
81349-mil-s-1950	00/115 government specification
Shelf Life:	
N/a	
Unit Of Measure	
Demilitarization	
No	
Fiig:	
A110a0	